

Studies of radiation hardness of Silicon Carbide detectors at n_TOF

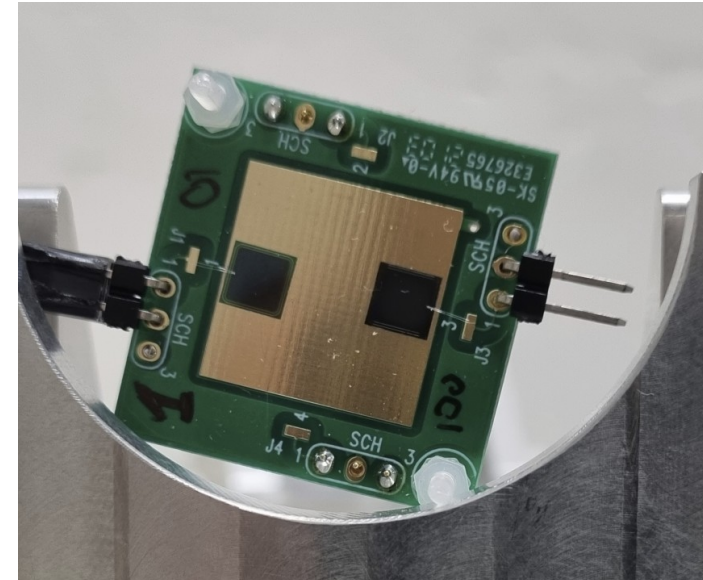
SiC detectors are an alternative for Silicon detectors for harsh environments that require higher durability and resistance to the damage of charge particles, gamma and neutrons.

While irradiation with ions have been already performed in the last years, studies involving neutrons (especially high energy) are lacking.

Physical property	4H-SiC	Si	Diamond
Energy gap (eV)	3.26	1.12	5.45
Displacement energy (eV)	30-40	13-15	40-45

Two SiC mounted on the same board were provided by LNS, both 5x5 mm² but different thickness (10 and 100 um).

New generation SiC with low depletion voltage (about 350V, instead of 800V).

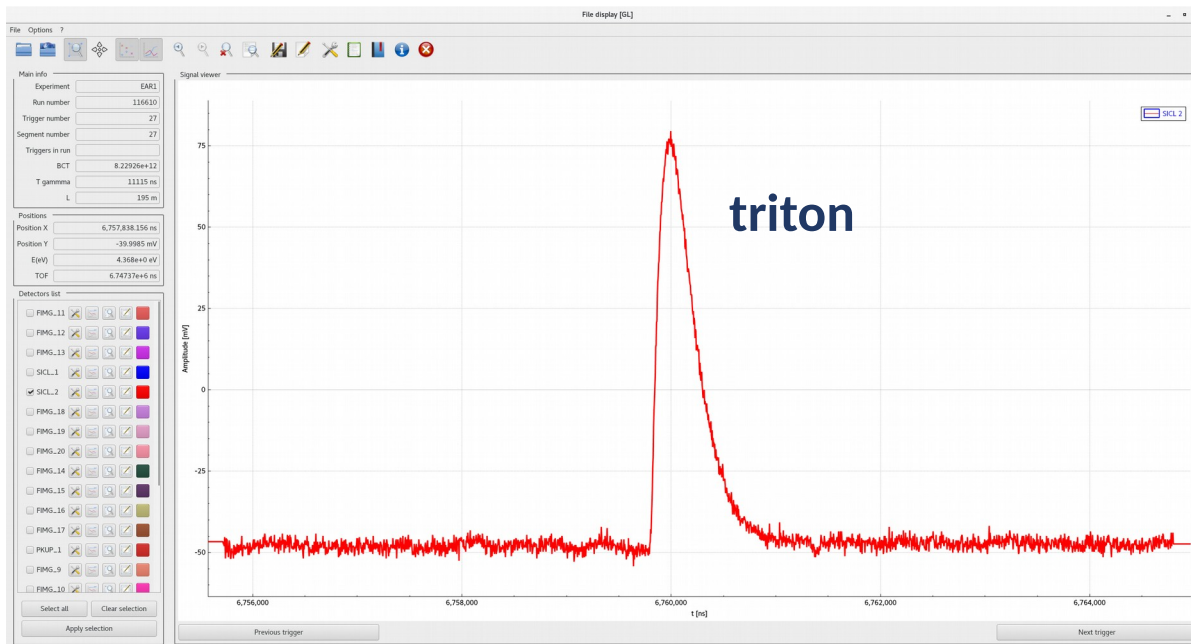


Three irradiation were performed from July to October:

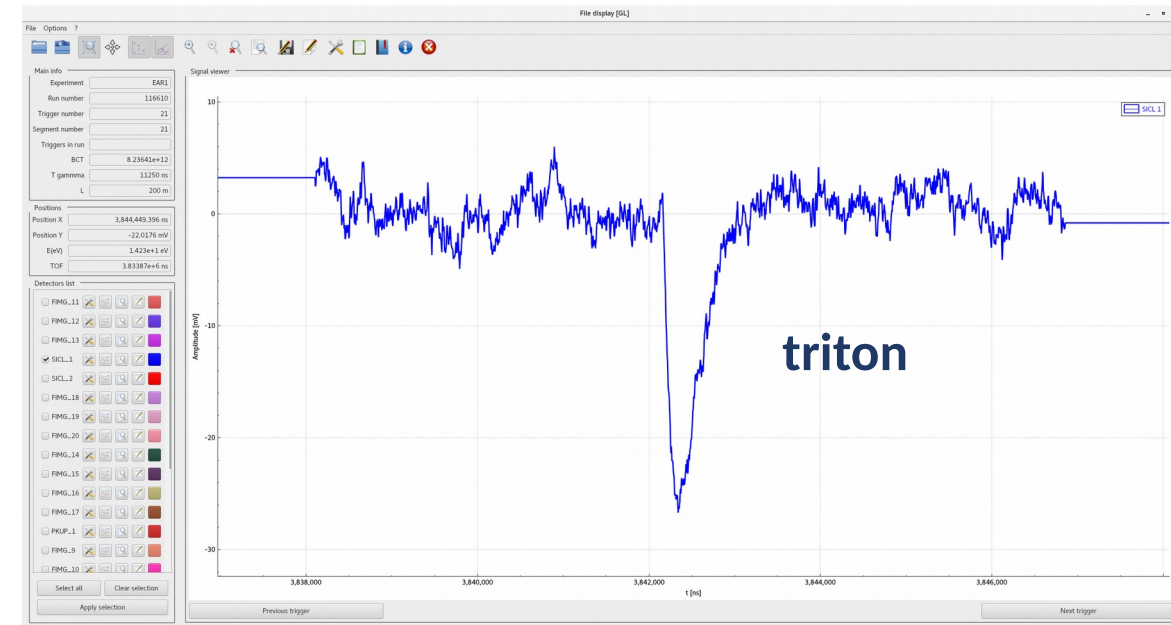
- 1 week in-beam in EAR1 with ${}^6\text{LiF}$ sample in air - active (high energy neutrons and low flux and to determine response to gflash)
- 1 week in-beam in NEAR - passive (high fluence)
- 4 weeks in-beam in EAR2 with ${}^6\text{LiF}$ sample in vacuum - active (response to thermal neutrons and g-flash)



Data acquired with TFA, good signal/noise for the 100um, worst for 10um (expected - higher capacitance).

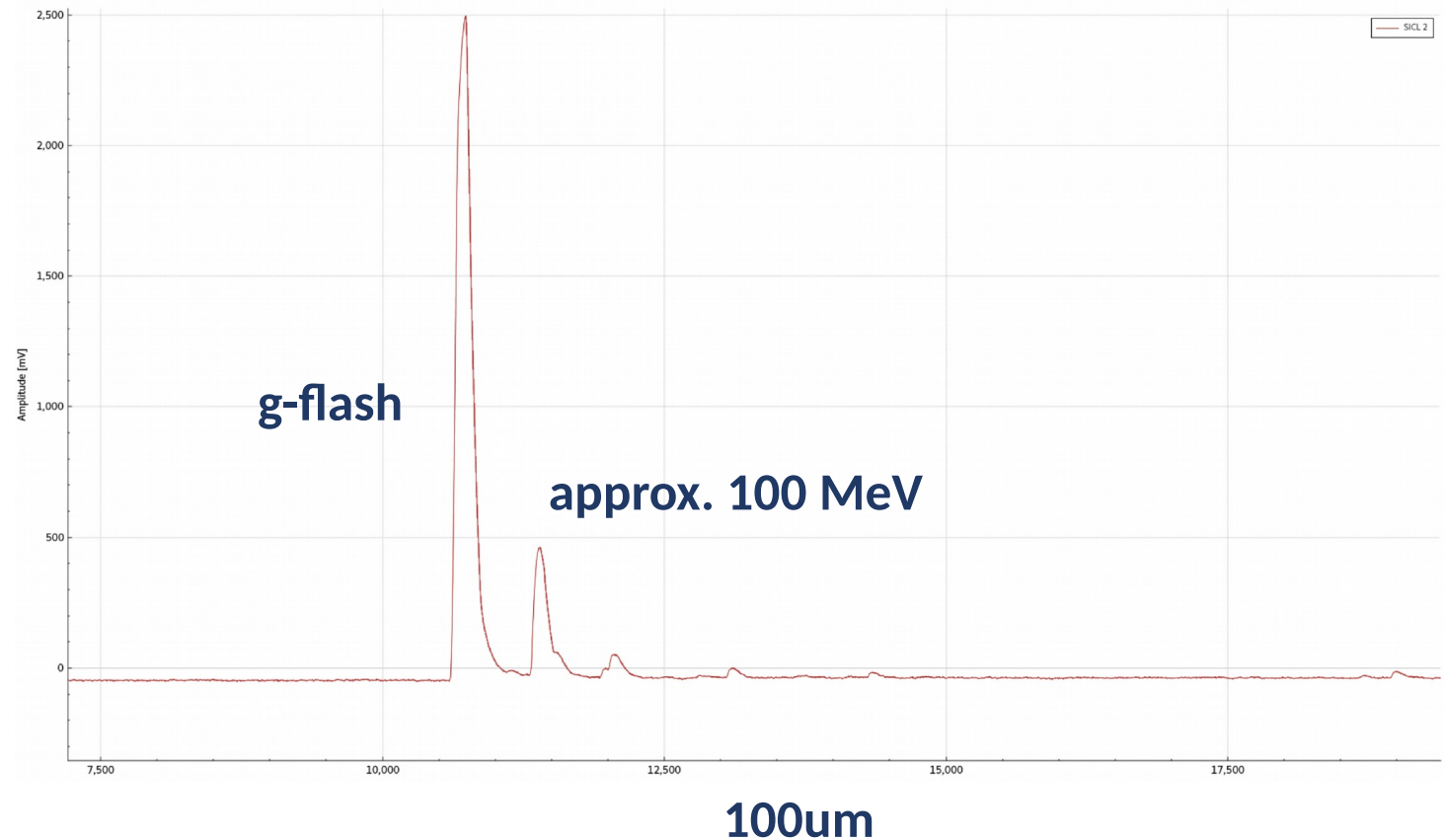


100um

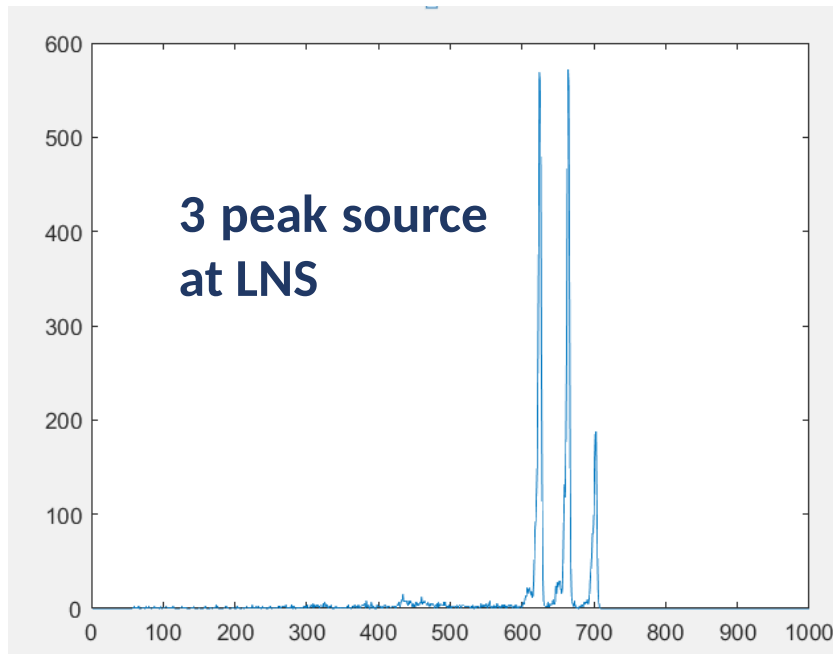


10um

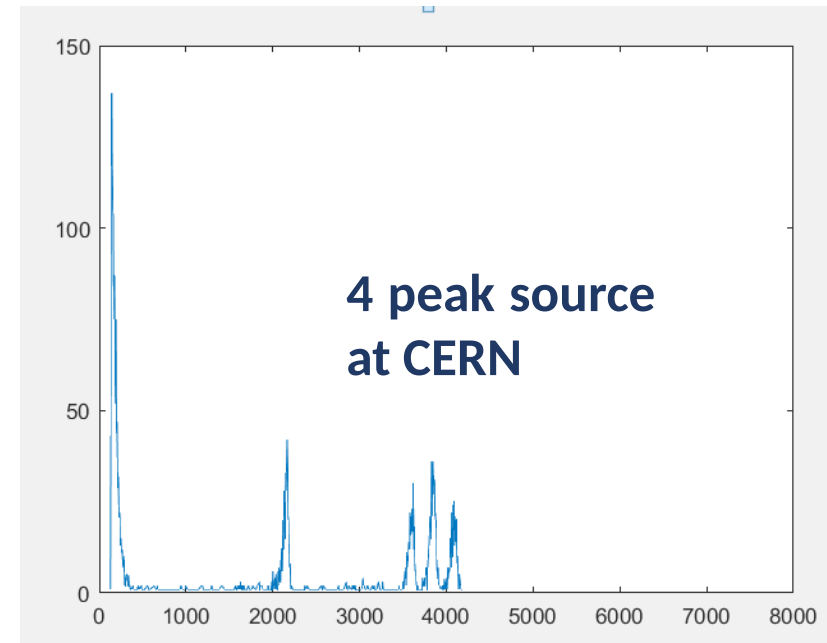
With proper parameters for Shaping a tof of few hundreds of ns can be reached (neutron energy of about 100 MeV).



Degradation for the 100um after one week in NEAR is visible, resolution for the ^{241}Am peak drops from 0.8% to 2.4% even if it can be partially compensated by increasing the Vbias.

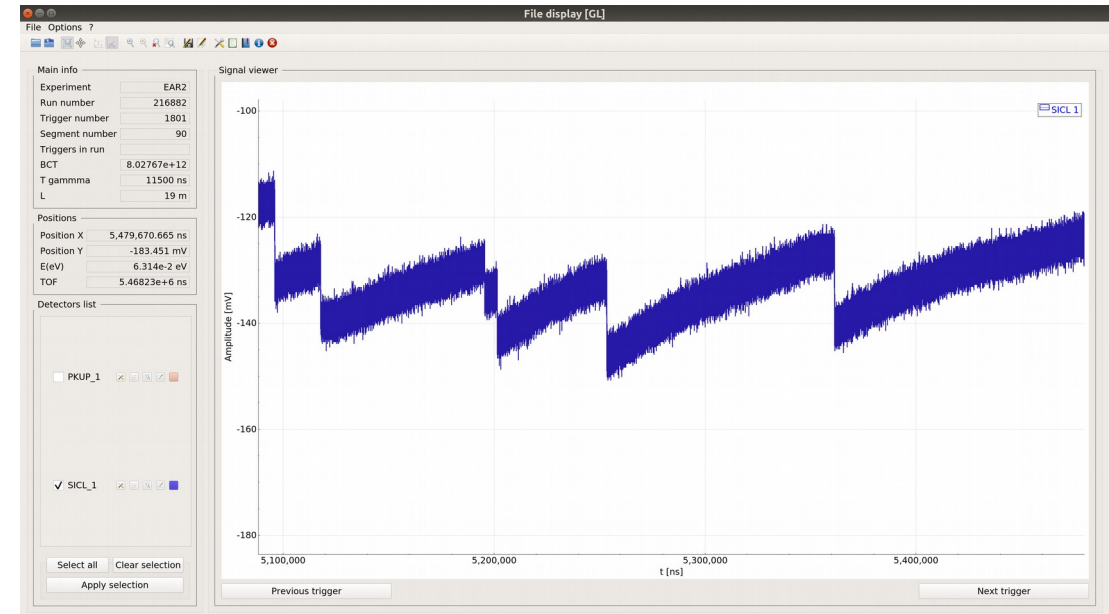
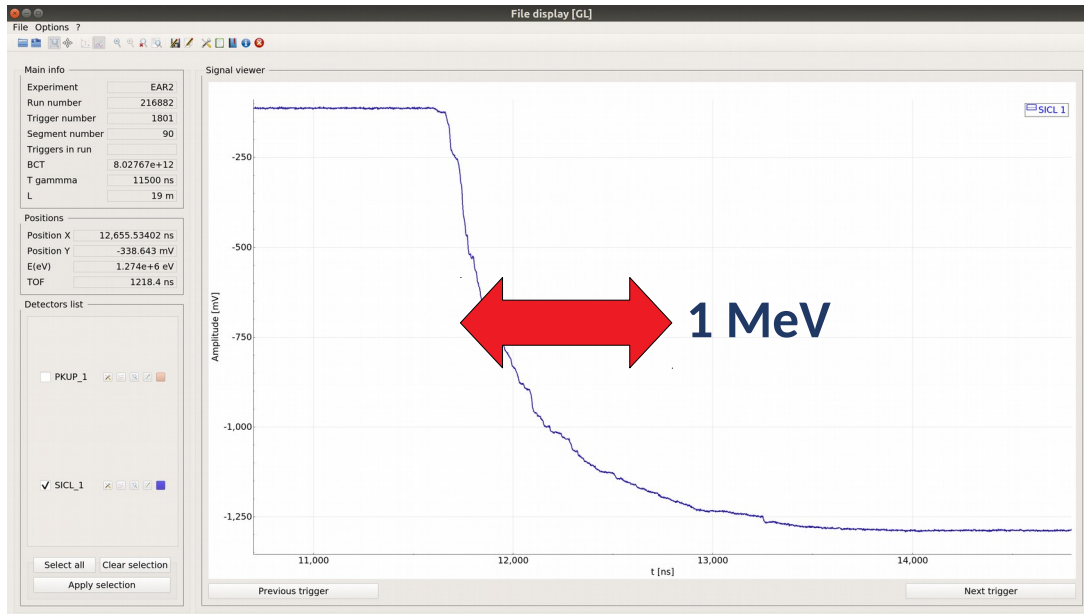


1 week in NEAR

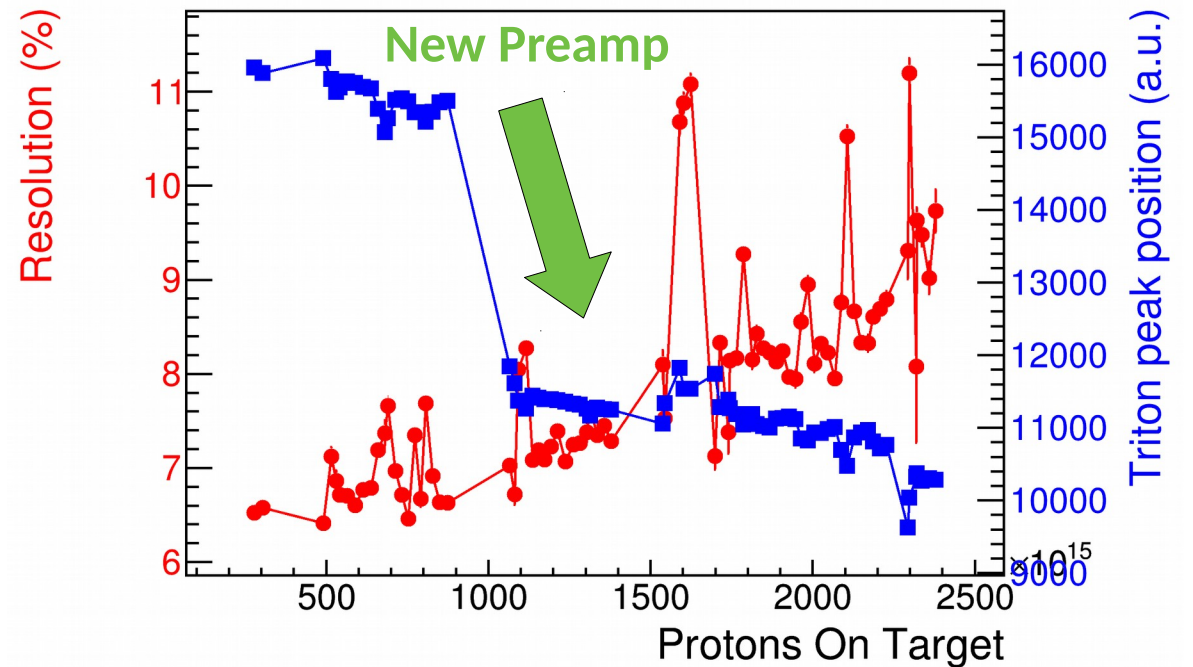
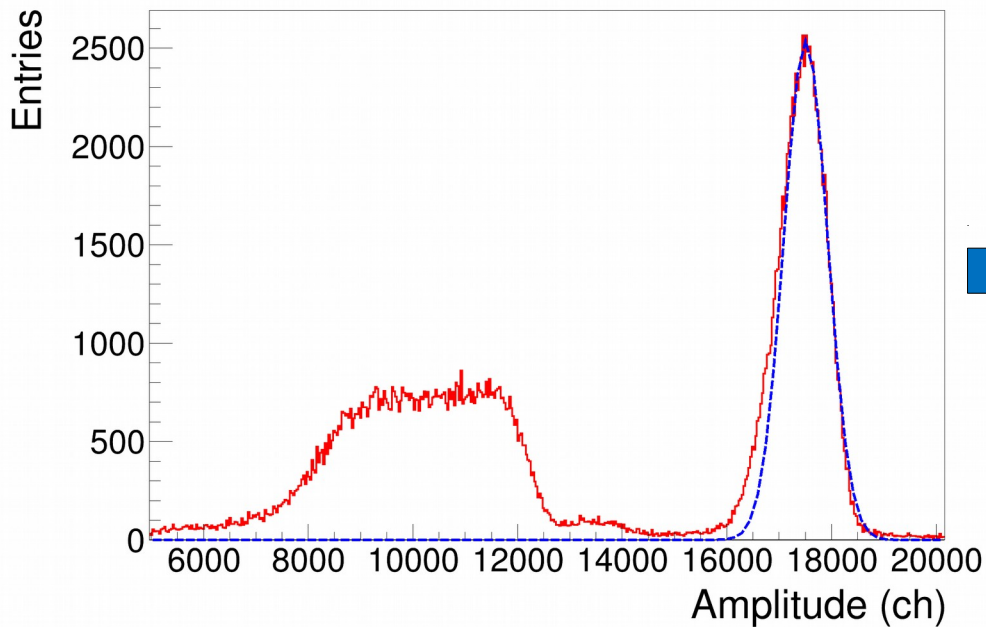


Courtesy of C. Altana

A bit tricky to judge the g-flash, we are ok after about 1 us (about 1 MeV), before we are affected by the material in front (thick window and support), we are perfectly ok at lower energies (of course).

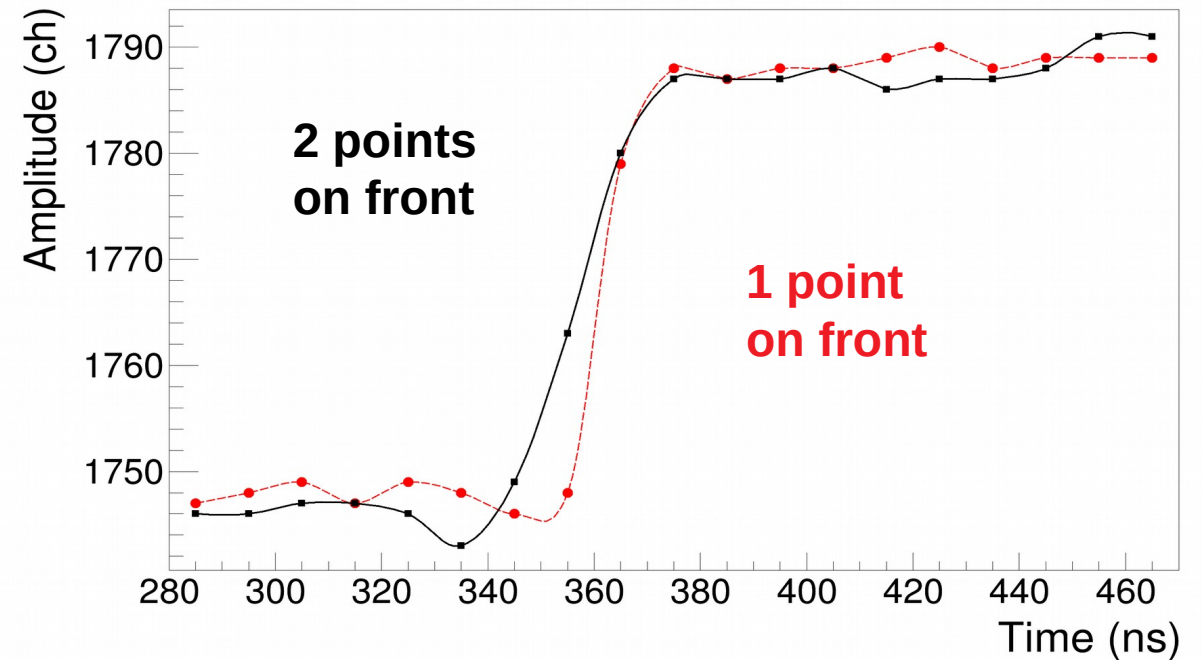
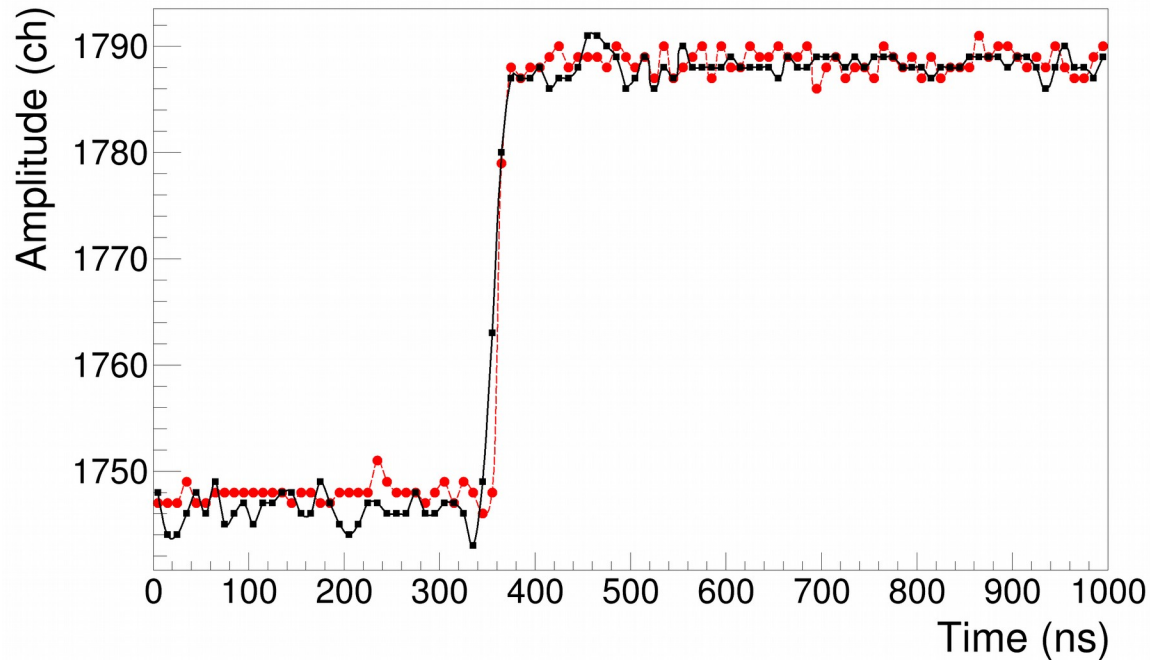


Stability of the detector in EAR2 was monitored considering mean and resolution of the triton peak.

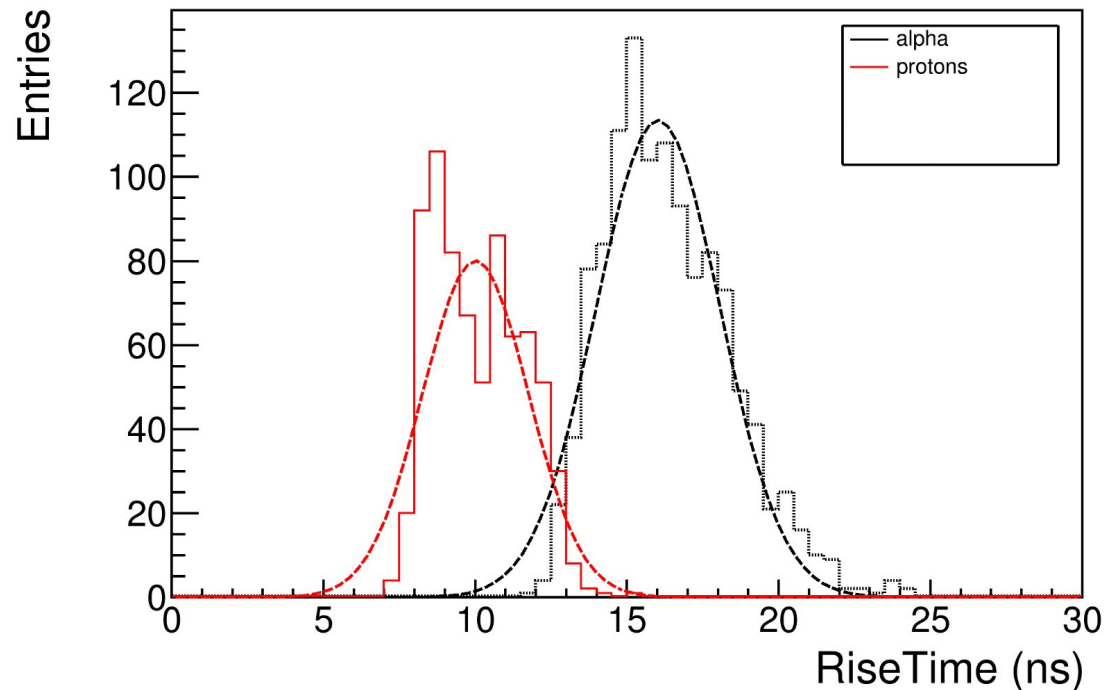


Detector survived 1 month of EAR2, with slightly worsening of the resolution (not fully depleted).

Experimental campaign at ILL to evaluate pulse shape feasibility for light particles, we collected waveforms (Alpha and **Proton** at 2.7 MeV below) at 100 MHz rate (totally not enough).



Data collected at ILL with light particles suggest that pulse shape can be applied for SiC to discriminate alpha from proton&tritons (even with only one single parameter).



FOM alpha/tritons at 2.7 MeV is around 0.7
(considered a good separation)

Same pulse shape routine of the Annular (G.Vecchio et al.)

When a more detailed analysis will be done new activities will be evaluated as:

- active NEAR irradiation (diamond like)
- studies of pulse shape discrimination
- longer parasitic run in EAR2 with a new detector (we used one that was already in NEAR, with degraded resolution) with background estimation to further investigate their use for physics.



LOI in 2024